

## 30V N-Channel Enhancement Mode MOSFET

Voltage

30 V

Current

4.4A

#### **Features**

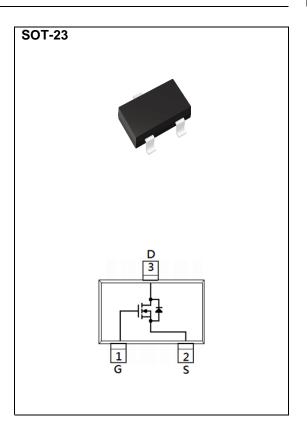
- $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_{D}@4.4A<48m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_{D}@3.6A<53m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@2.5V$ ,  $I_{D}@2.5A < 66m\Omega$
- $\bullet \ R_{DS(ON)}, \ V_{GS}@1.8V, \ I_{D}@1.5A{<}92m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

• Case: SOT-23 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.009 grams



# **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	30	V	
Gate-Source Voltage	V <sub>G</sub> s	<u>+</u> 12			
Continuous Drain Current (Note 4)		I <sub>D</sub>	4.4	A	
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	17.6		
Power Dissipation	T <sub>a</sub> =25°C	P <sub>D</sub>	1.25	W	
	Derate above 25°C		10	mW/°C	
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C	
Typical Thermal Resistance		D	100	°C/W	
- Junction to Ambient (Note 3,4)		Reja	100		



## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	30	-	- V		
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	0.4	0.72	1.2	V	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =4.4A	-	37	48	mΩ	
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =3.6A	-	40	53		
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =2.5A	-	48	66		
		V <sub>GS</sub> =1.8V, I <sub>D</sub> =1.5A	-	62	92		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V	-	-	1	uA	
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 12V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA	
Dynamic (Note 5)							
Total Gate Charge	$Q_g$	15)/ 15	-	11.3	-	nC	
Gate-Source Charge	$Q_gs$	V <sub>DS</sub> =15V, I <sub>D</sub> =4.4A, V <sub>GS</sub> =10V (Note 1,2)	-	1	-		
Gate-Drain Charge	$Q_gd$	VGS=10V (1000 1,2)	-	1.2	-		
Input Capacitance	Ciss	\/ 45\/ \/ 0\/	-	447	-	pF	
Output Capacitance	Coss	V <sub>DS</sub> =15V, V <sub>GS</sub> =0V, f=1MHZ	-	34	-		
Reverse Transfer Capacitance	Crss	I=IIVIDZ	-	22	-		
Turn-On Delay Time	td <sub>(on)</sub>	\/ 45\/ I 44A	-	1.7	-		
Turn-On Rise Time	tr	V <sub>DD</sub> =15V, I <sub>D</sub> =4.4A,	-	38	-	ns	
Turn-Off Delay Time	td <sub>(off)</sub>	V <sub>GS</sub> =10V, R <sub>G</sub> =3Ω (Note 1,2)	-	82	-		
Turn-Off Fall Time	tf	RG=312 (Note 1,2)	-	64	-		
Drain-Source Diode							
Maximum Continuous Drain-Source Diode Forward Current	Is		-	-	1.5	Α	
Diode Forward Voltage	V <sub>SD</sub>	Is=1A, V <sub>GS</sub> =0V	-	0.77	1.2	V	

#### NOTES:

- 1. Pulse width<a>300us</a>, Duty cycle<a>2%</a>.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.



#### **TYPICAL CHARACTERISTIC CURVES**

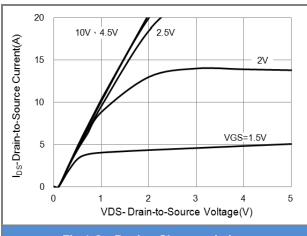
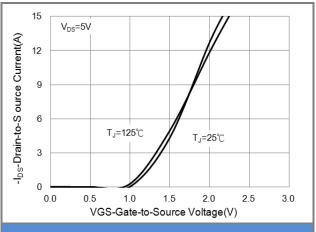


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

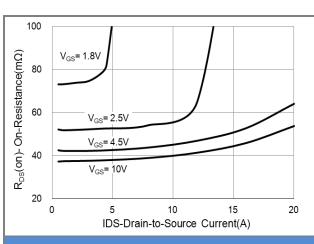


Fig.3 On-Resistance vs. Drain Current

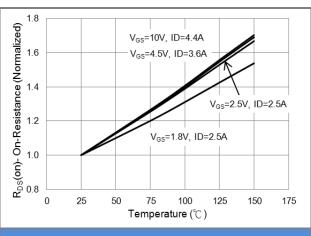


Fig.4 On-Resistance vs. Junction temperature

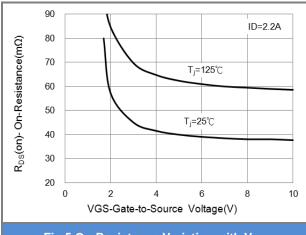
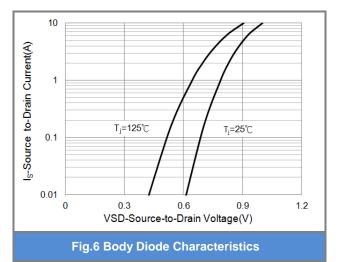


Fig.5 On-Resistance Variation with V<sub>GS</sub>



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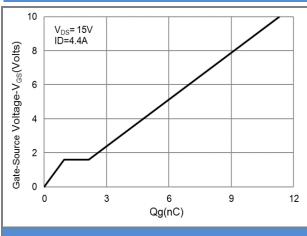


Fig.7 Gate-Charge Characteristics

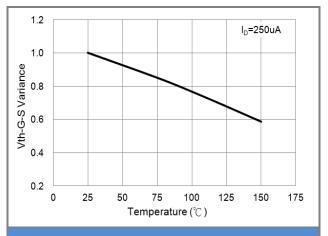


Fig.8 Threshold Voltage Variation with Temperature

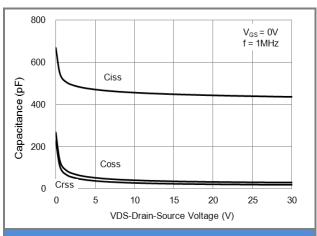


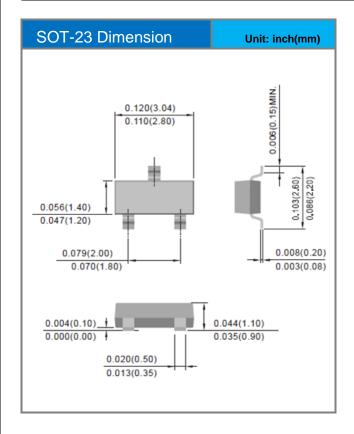
Fig.9 Capacitance vs. Drain-Source Voltage

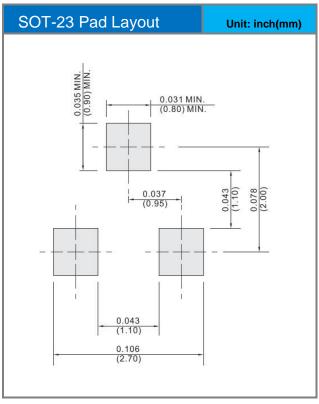


## **Product and Packing Information**

Part No.	Package Type	Packing Type	Marking	
PJA3402-AU	SOT-23	3K pcs / 7" reel	A02	

# **Packaging Information & Mounting Pad Layout**







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